Supporting Information

Enhanced electrical conductivity and photoconductive properties of

Sn-doped Sb₂Se₃ crystals

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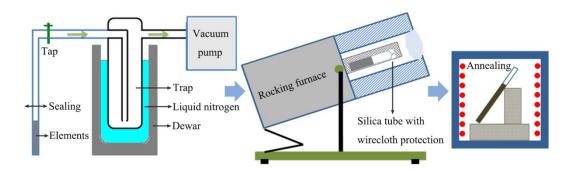


Fig. S1 Schematic illustration of the $(Sn_xSb_{1-x})_2Se_3$ crystals preparation process.

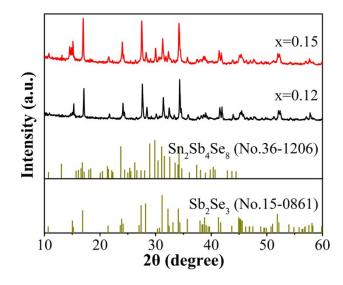


Fig. S2 XRD patterns of the powdered $(Sn_xSb_{1-x})_2Se_3$ samples (x=0.12 and 0.15).

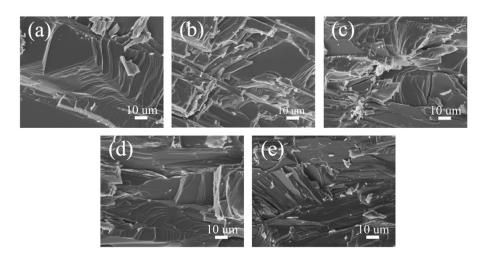


Fig. S3 (a-e) SEM images of the fractured surface of $(Sn_xSb_{1-x})_2Se_3$ crystals with Sn concentration x of 0.00, 0.03, 0.05, 0.07 and 0.10, respectively.

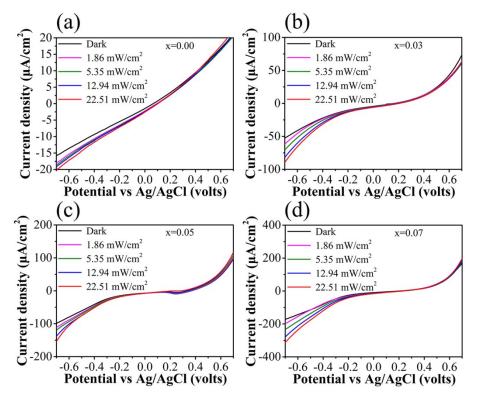


Fig. S4 Current-voltage characteristics at different power densities of the $(Sn_xSb_{1-x})_2Se_3$ crystals at x=0.00 (a), x=0.03 (b), x=0.05 (c) and x=0.07 (d).